



Open Loop Hall Current Sensor CYHCT-FV

This Hall Effect current sensor is based on open loop principle and designed with a high galvanic isolation between primary conductor and secondary circuit. It can be used for measurement of DC current, DC pulse currents etc. The output of the transducer reflects the real wave of the current carrying conductor.

Product Characteristics	Applications
<ul style="list-style-type: none"> • Excellent accuracy • Very good linearity • Less power consumption • Window structure • Electrically isolating the output of the transducer from the current carrying conductor • No insertion loss • Current overload capability 	<ul style="list-style-type: none"> • Photovoltaic equipment • Frequency conversion timing equipment • Various power supply • Uninterruptible power supplies (UPS) • Electric welding machines • Transformer substation • Numerical controlled machine tools • Electric powered locomotive • Microcomputer monitoring • Electric power network monitoring

Electrical Data

Primary Nominal DC Current I_r (A)	Measuring Range (A)	DC Output Voltage (V)	Window size (mm)	Part number
200	0~±200	x=0: 0-4V ±1.0% x=3: 0-5V ±1.0% x=8: 0-10V ±1.0%	41x14	CYHCT-FV-U/B200A-xn
400	0~±400			CYHCT-FV-U/B400A-xn
500	0~±500			CYHCT-FV-U/B500A-xn
600	0~±600			CYHCT-FV-U/B600A-xn
800	0~±800			CYHCT-FV-U/B800A-xn
1000	0~±1000			CYHCT-FV-U/B1000A-xn
2000	0~±2000			CYHCT-FV-U/B2000A-xn

(n=2, V_{cc} = +12VDC±5%;; n=3, V_{cc} =+15VDC±5%;; n=4, V_{cc} =+24VDC±5%;,

U: unidirectional input current; B: bidirectional input current, please give U or B in Part number)

Supply Voltage	V_{cc} = +12V, +15V, +24VDC ± 5%
Output Voltage at I_r , $T_A=25^\circ\text{C}$:	V_{out} =0- 4V, 0-5V, 0-10VDC
Current Consumption	I_c < 25mA
Galvanic isolation, 50/60Hz, 1min:	3kV rms
Output Impedance:	R_{out} < 150Ω
Load resistance:	10kΩ

Accuracy and Dynamic performance data

Accuracy at I_r , $T_A=25^\circ\text{C}$,	X <±1.0% FS
Linearity from 0 to I_r , $T_A=25^\circ\text{C}$,	E_L <±0.5% FS
Electric Offset Voltage, $T_A=25^\circ\text{C}$,	V_{oe} <50mV
Magnetic Offset Voltage ($I_r \rightarrow 0$)	V_{om} <±20mV
Thermal Drift of Offset Voltage,	V_{ot} <±1.0mV/°C
Response Time at 90% of I_P ($f=1\text{k Hz}$)	t_r < 1ms
Case Material:	PBT, heat resistant 100°C
	flame retardant
Frequency Bandwidth (-3dB),	f_b = DC - 20 kHz

